



JLS45BGS3-2L

1-Line Bi-directional High Power TVS Diode

Jalan-Microelectronics

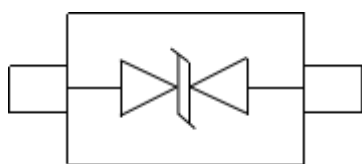
Description

The JLS45BGS3-2L is a bi-directional high power TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The JLS45BGS3-2L complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into an ultra-small lead-free SOD-323 package. The small size and high ESD surge protection make JLS45BGS3-2L an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- * 1350W peak pulse power (8/20 μs)
- * Low leakage:nA level
- * Operating voltage: 4.5V
- * Ultra low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 100A (8/20 μs)
- * RoHS Compliant
- * Package: SOD-323

Circuit Diagram

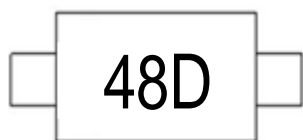


Circuit and Pin Schematic

Applications

- * Fast-charge battery chargers
- * Power management system
- * Cellular Handsets and Accessories
- * Personal Digital Assistants
- * Notebooks and Handhelds
- * Portable Instrumentation
- * Digital Cameras

Marking Diagram



Transparent top view

48D:Device Marking Code

Ordering Information

Part Number	Packaging	Reel Size
JLS45BGS3-2L	3000/Tape & Reel	7 inch



JLS45BGS3-2L

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

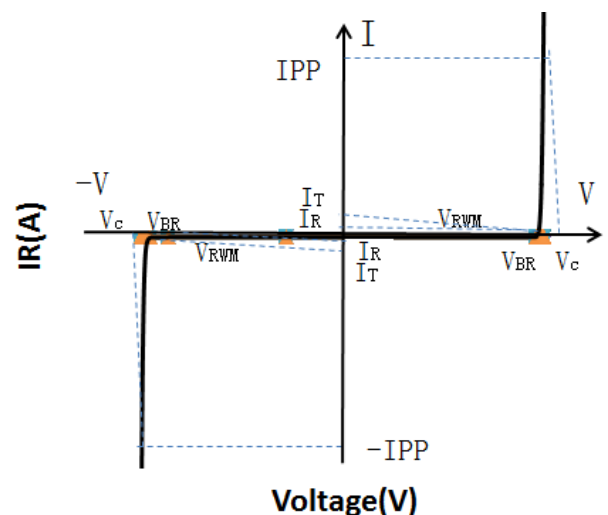
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	1350	W
Peak Pulse Current (8/20 μs)	IPP	100	A
ESD per IEC 61000-4-2 (Air)	VESD	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	
Operating Temperature Range	TJ	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				4.5	V
Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	4.7			V
Reverse Leakage Current	I_R	$V_{RWM} = 4.5\text{V}$			1	μA
Clamping Voltage	V_C	$I_{PP} = 20\text{A}$ (8 x 20 μs pulse)			7.8	V
Clamping Voltage	V_C	$I_{PP} = 100\text{A}$ (8 x 20 μs pulse)			13.5	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$			300	pF

Portion Electronics Parameter

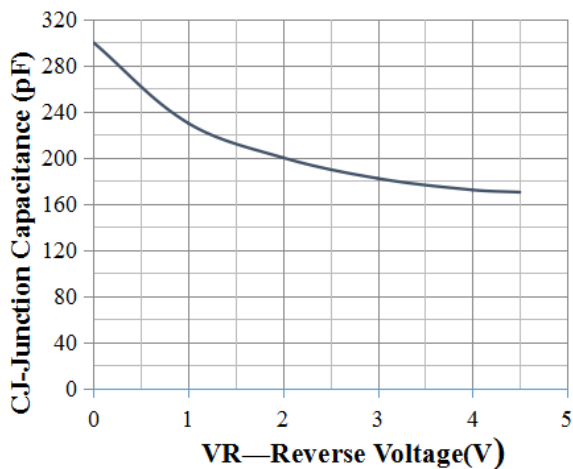
Symbol	Parameter
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_C



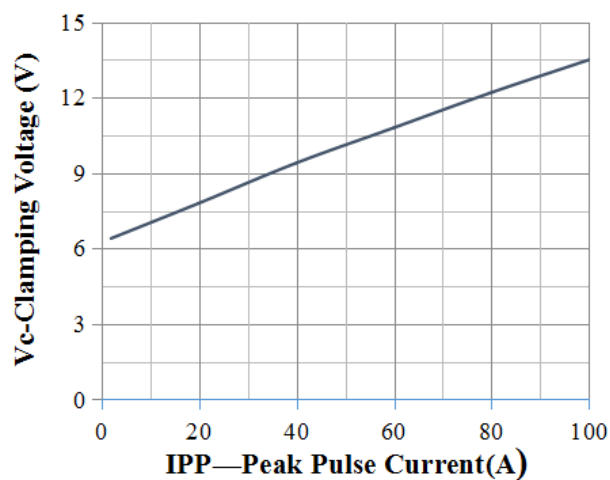


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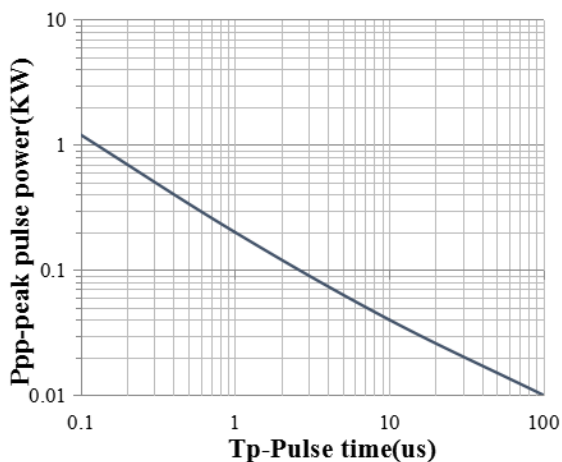
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



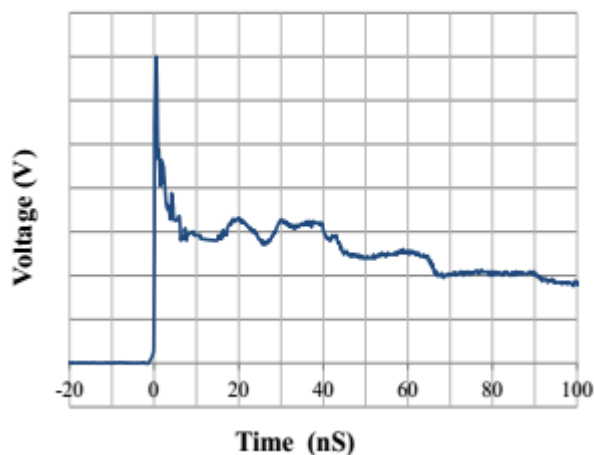
Junction Capacitance vs. Reverse Voltage



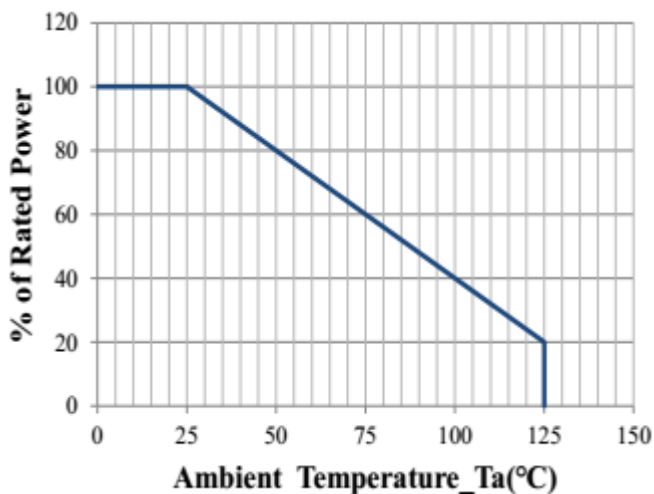
Clamping Voltage vs. Peak Pulse Current



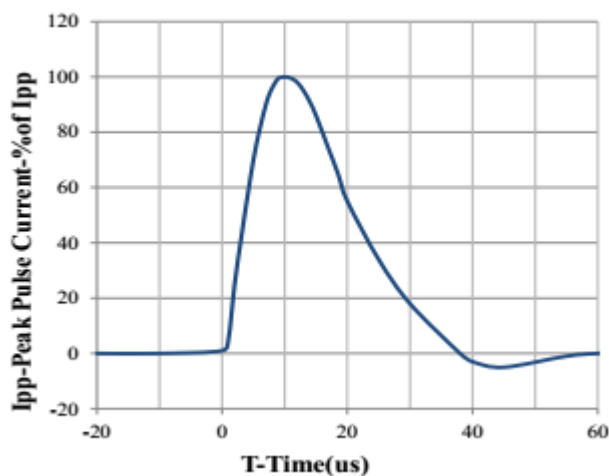
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform



Power Derating Curve

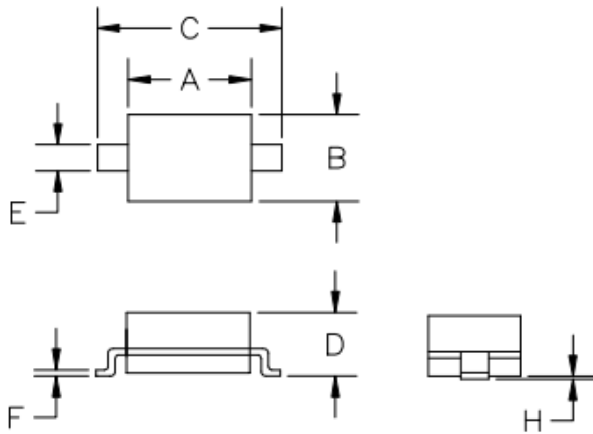


8 X 20us Pulse Waveform



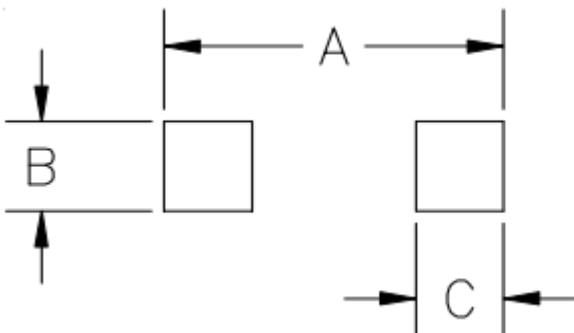
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SOD-323 Package Outline Drawing (Dimensions in millimeters)



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.80	0.060	0.071
B	1.20	1.40	0.045	0.054
C	2.30	2.70	0.090	0.107
D	-	1.10	-	0.043
E	0.30	0.40	0.012	0.016
F	0.10	0.25	0.004	0.010
H	-	0.10	-	0.004

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031

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